

**Amplifier, Power, 0.5W  
12.7-15.4 GHz**

**MAAP-000044-PKG003**  
Rev A  
Preliminary Datasheet

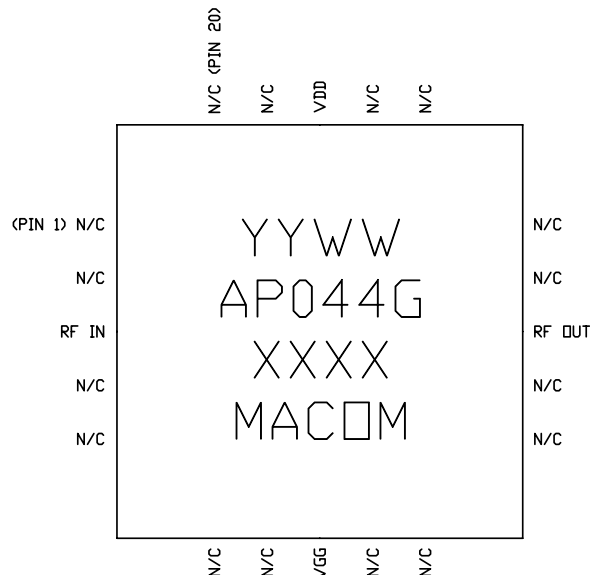
**Features**

- ◆ 0.5 Watt Saturated Output Power Level
- ◆ Variable Drain Voltage (6-10V) Operation
- ◆ MSAG™ Process
- ◆ 5x5 mm 20 Lead MLP Package

**Description**

The MAAP-000044-PKG0003 is a 3-stage 0.5 W power amplifier with on-chip bias networks in a 20 lead MLP package, allowing easy assembly. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Each device is 100% RF tested to ensure performance compliance. The part is fabricated using M/A-COM's GaAs Multifunction Self-Aligned Gate (MSAG™) Process.



**Primary Applications**

- ◆ **Point-to-Point Radio**
  - ◇ 13 and 15 GHz Bands
- ◆ **SatCom**
- ◆ **Radio Communications**

**Also Available in:**

		SAMPLE BOARD
Description	Die	Plastic Package
Part Number	MAAPGM0044-DIE	MAAP-000044-SMB003

**Electrical Characteristics:  $T_C = 30^\circ C^1$ ,  $Z_0 = 50\Omega$ ,  $V_{DD} = 8V$ ,  $I_{DQ} = 210 mA^2$ ,  $P_{in} = 14dBm$ ,  $R_G = 350\Omega$**

Parameter	Symbol	Typical	Units
Bandwidth	f	12.7-15.4	GHz
Output Power	$P_{OUT}$	27	dBm
Power Added Efficiency	PAE	22	%
1-dB Compression Point	$P_{1dB}$	26	dBm
Small Signal Gain	G	17	dB
Input VSWR	VSWR	2.5:1	—
Output VSWR	VSWR	2.2:1	—
Gate Supply Current	$I_{GG}$	< 2	mA
Drain Supply Current	$I_{DD}$	< 0.4	A
Output Third Order Intercept	OTOI	34	dBm
3 <sup>rd</sup> Order Intermodulation Distortion, Single Carrier Level = 16 dBm	IM3	-20	dBm

1.  $T_C$  = Case Temperature.
2. Adjust  $V_{GG}$  between -2.6 to -1.2 to achieve indicated  $I_{DQ}$ .

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### Maximum Ratings<sup>3</sup>

Parameter	Symbol	Absolute Maximum	Units
Input Power	$P_{IN}$	19.0	dBm
Drain Supply Voltage	$V_{DD}$	+12.0	V
Gate Supply Voltage	$V_{GG}$	-3.0	V
Quiescent Drain Current (No RF)	$I_{DQ}$	340	mA
Quiescent DC Power Dissipated (No RF)	$P_{DISS}$	3.4	W
Junction Temperature	$T_J$	170	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

3. Operation beyond these limits may result in permanent damage to the part.

### Recommended Operating Conditions<sup>4</sup>

Characteristic	Symbol	Min	Typ	Max	Unit
Drain Supply Voltage	$V_{DD}$	6.0	8.0	10.0	V
Gate Supply Voltage	$V_{GG}$	-2.6	-1.7	-1.2	V
Input Power	$P_{IN}$		14.0	17.0	dBm
Junction Temperature	$T_J$			150	°C
Thermal Resistance	$\Theta_{JC}$		33.4		°C/W
Package Base Temperature	$T_B$			Note 5	°C

4. Operation outside of these ranges may reduce product reliability.

5. Maximum Package Case Temperature = 170°C —  $\Theta_{JC} * V_{DD} * I_{DQ}$

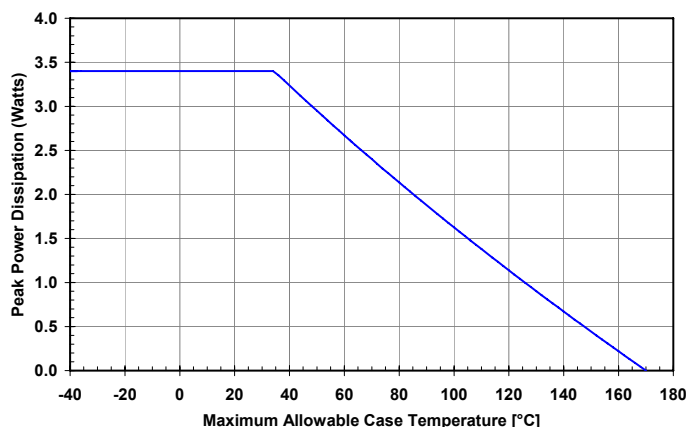


### Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

1. Apply  $V_{GG} = -1.7$  V,  $V_{DD} = 0$  V.
2. Ramp  $V_{DD}$  to desired voltage, typically 8 V.
3. Adjust  $V_{GG}$  to set  $I_{DQ}$ , (approximately @ -1.7V).
4. Set RF input.
5. Power down sequence in reverse. Turn gate voltage off last.

Power Derating Curve, Quiescent (No RF)



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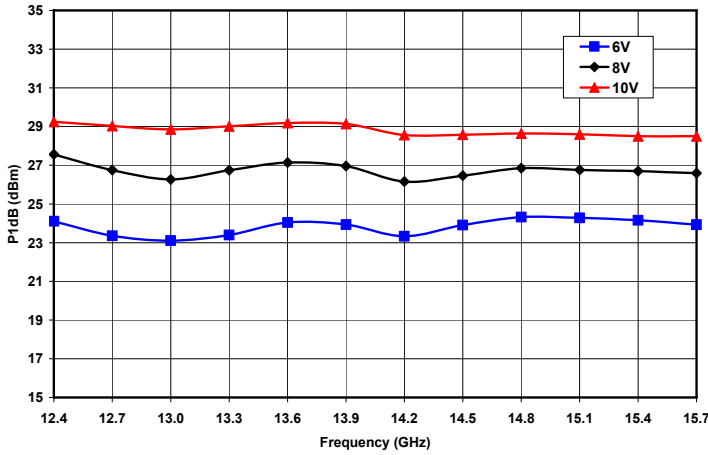


Figure 1. 1 dB Compression Point vs. Frequency and Drain Voltage at IDQ = 210mA

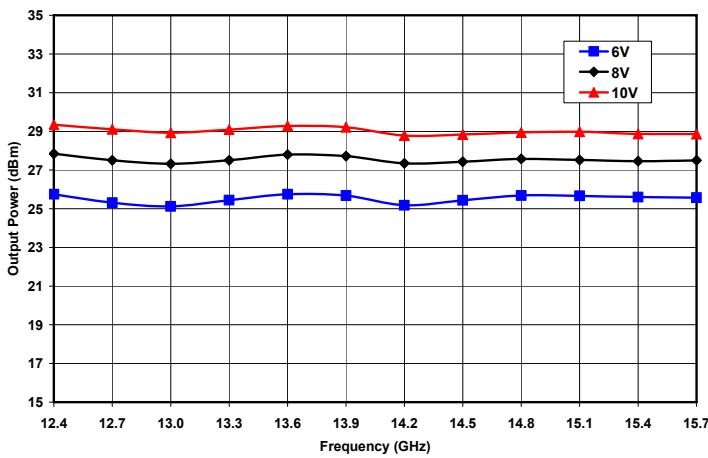


Figure 3. Saturated Output Power vs. Frequency and Drain Voltage at IDQ = 210mA

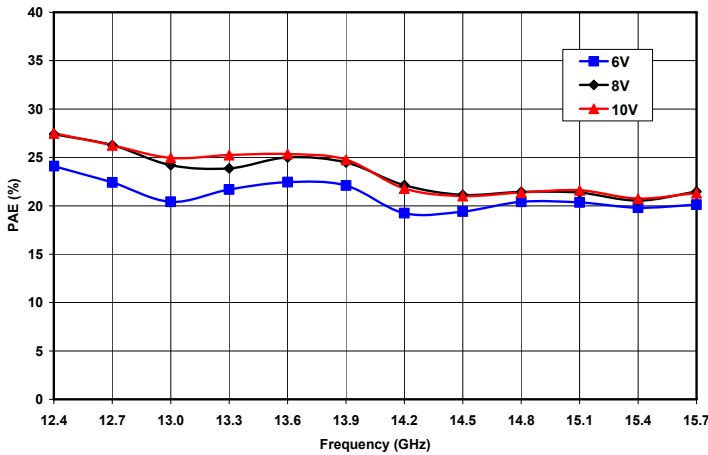


Figure 5. Saturated Power Added Efficiency vs. Frequency and Drain Voltage at IDQ = 210mA

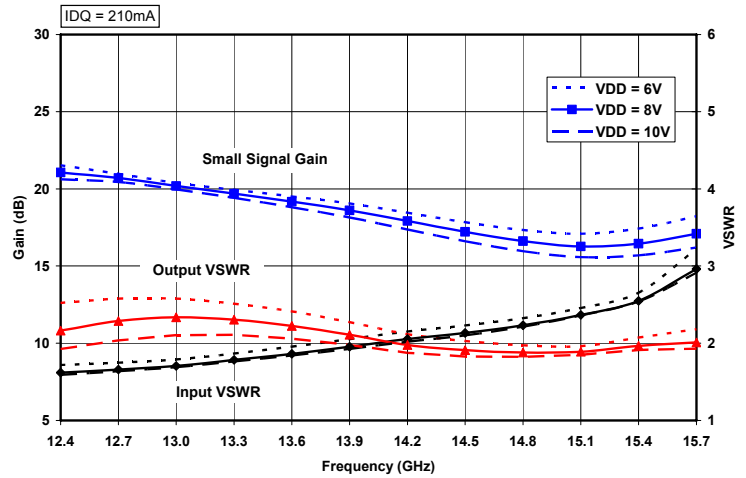


Figure 2. Small Signal Gain and Input & Output VSWR vs. Frequency and Drain Voltage at IDQ = 210mA

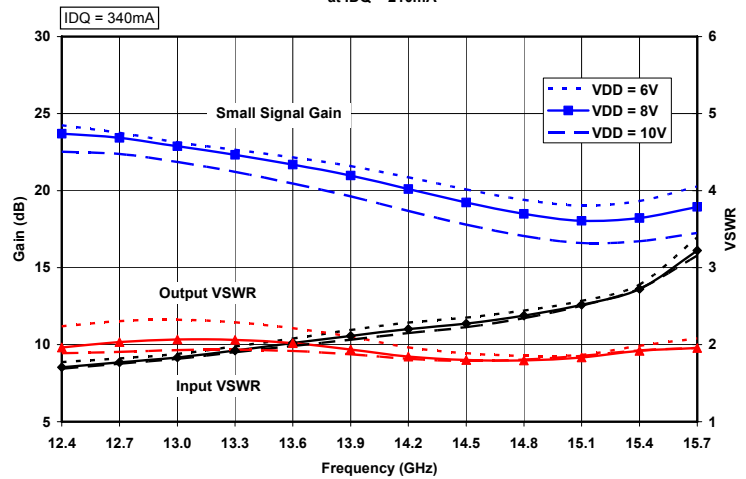


Figure 4. Small Signal Gain and Input & Output VSWR vs. Frequency and Drain Voltage at IDQ = 340mA

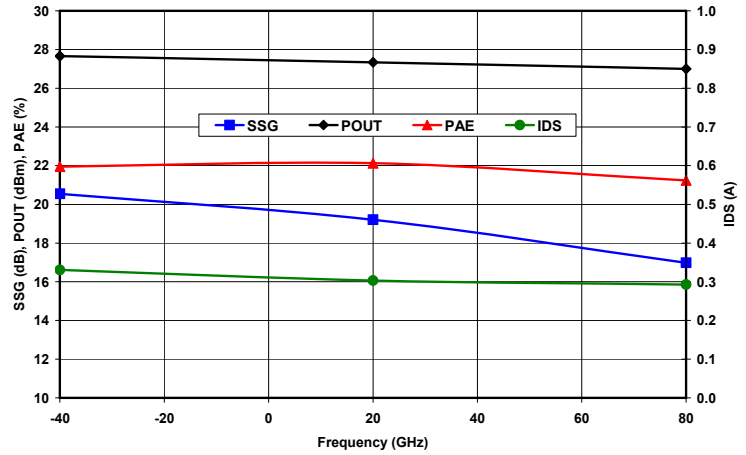


Figure 6. Small Signal Gain & Saturated Output Power, Power Added Efficiency and Drain Current vs. Case Temperature at 14.2 GHz, VD = 8V and IDQ = 210mA

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**VD = 6V**

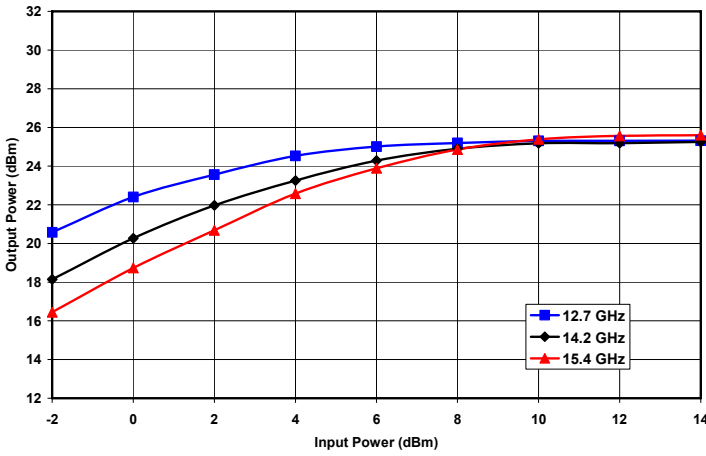


Figure 7. Output Power vs. Input Power and Frequency at VD = 6V and IDQ = 210mA

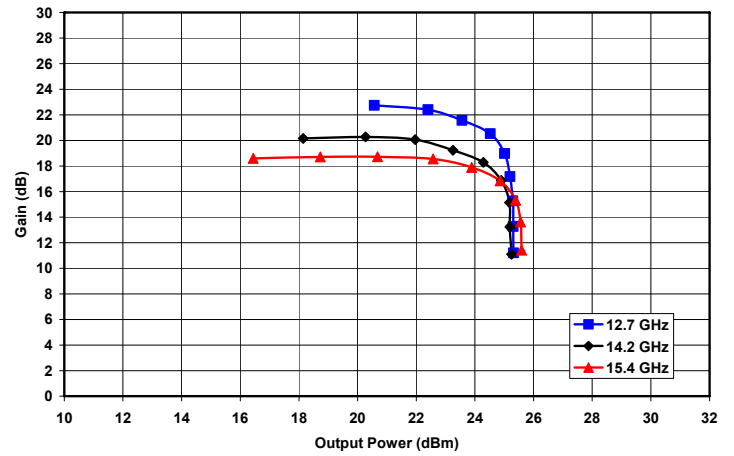


Figure 8. Gain vs. Output Power and Frequency at VD = 6V and IDQ = 210mA

**VD = 8V**

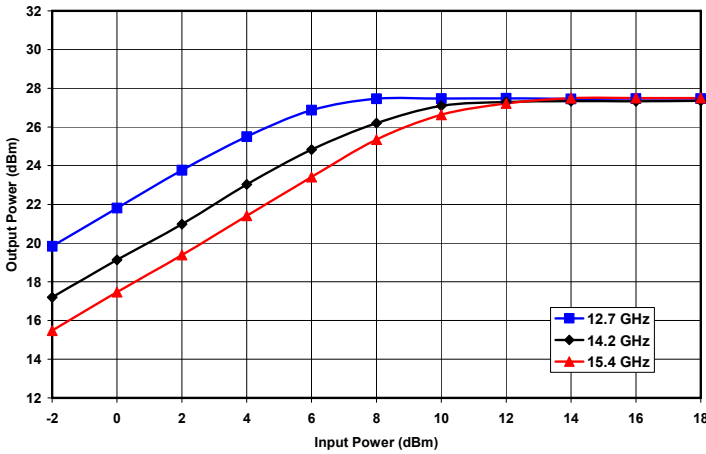


Figure 9. Output Power vs. Input Power and Frequency at VD = 8V and IDQ = 210mA

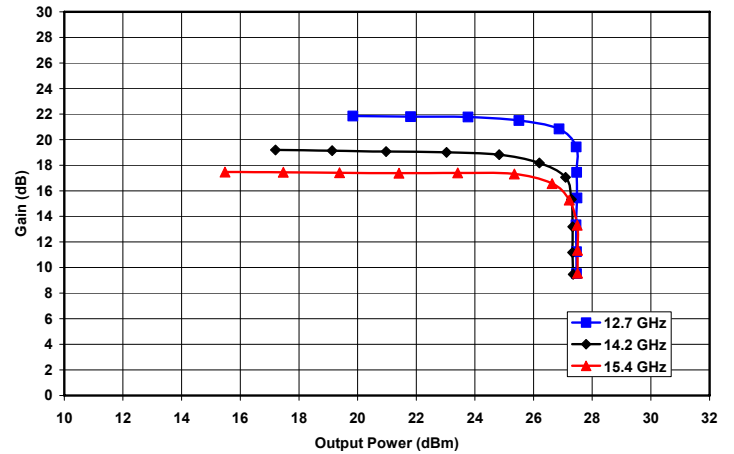


Figure 10. Gain vs. Output Power and Frequency at VD = 8V and IDQ = 210mA

**VD = 10V**

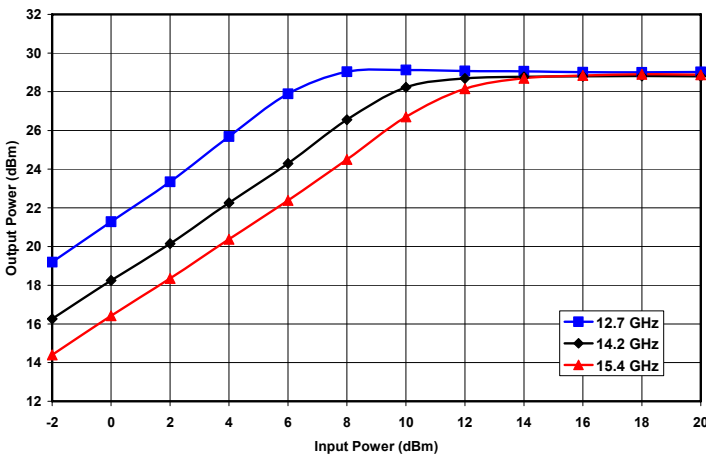


Figure 11. Output Power vs. Input Power and Frequency at VD = 10V and IDQ = 210mA

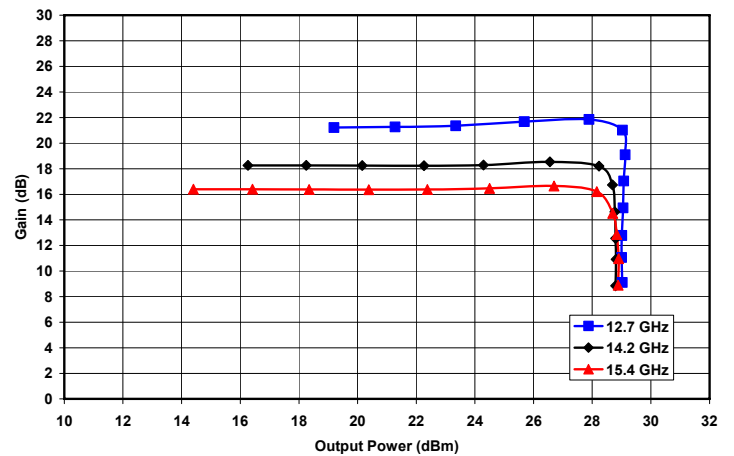


Figure 12. Gain vs. Output Power and Frequency at VD = 10V and IDQ = 210mA

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**VD = 6V**

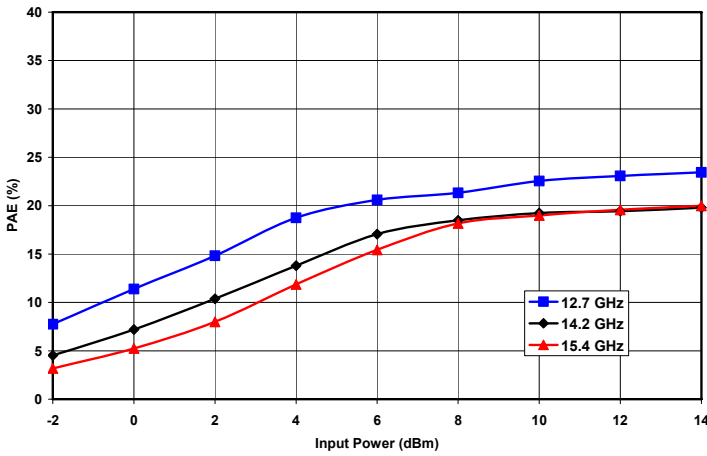


Figure 13. Power Added Efficiency vs. Input Power and Frequency at VD = 6V and IDQ = 210mA

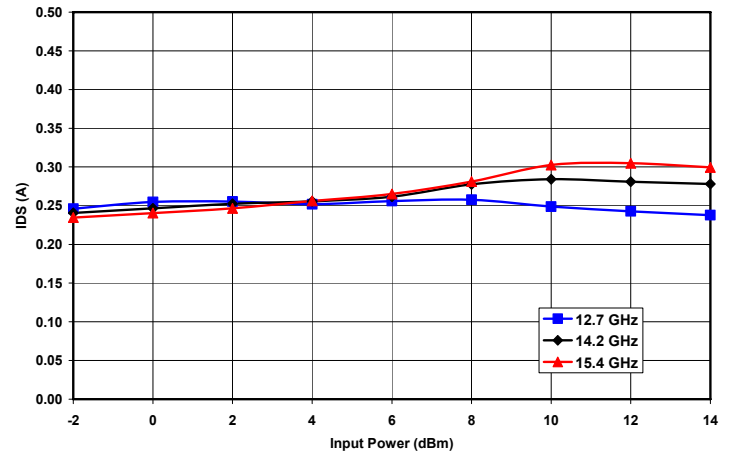


Figure 14. Drain Current vs. Input Power and Frequency at VD = 6V and IDQ = 210mA

**VD = 8V**

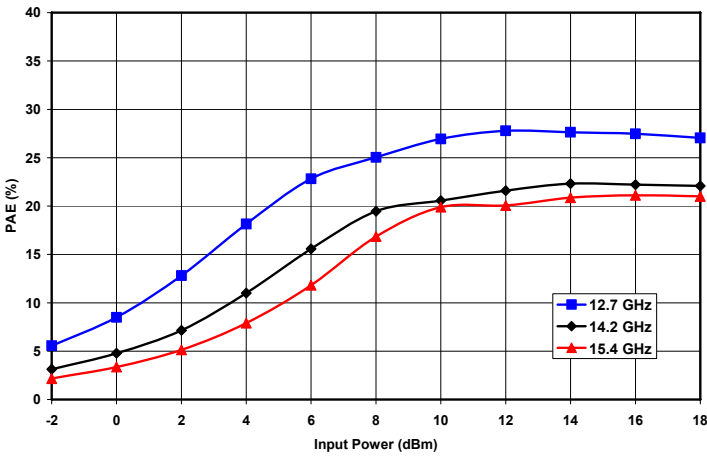


Figure 15. Power Added Efficiency vs. Input Power and Frequency at VD = 8V and IDQ = 210mA

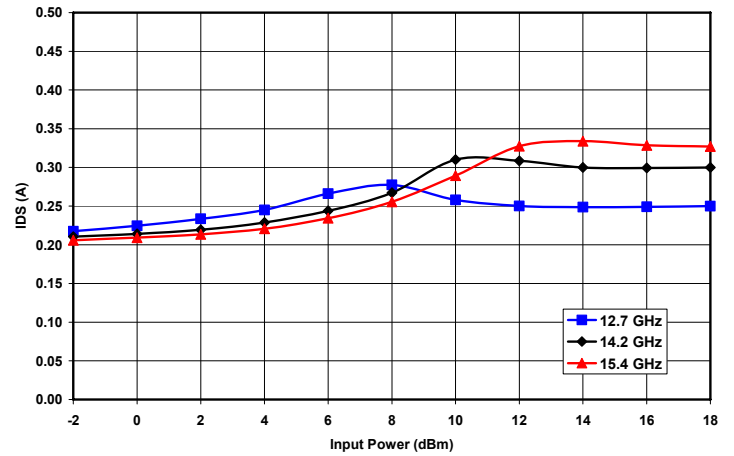


Figure 16. Drain Current vs. Input Power and Frequency at VD = 8V and IDQ = 210mA

**VD = 10V**

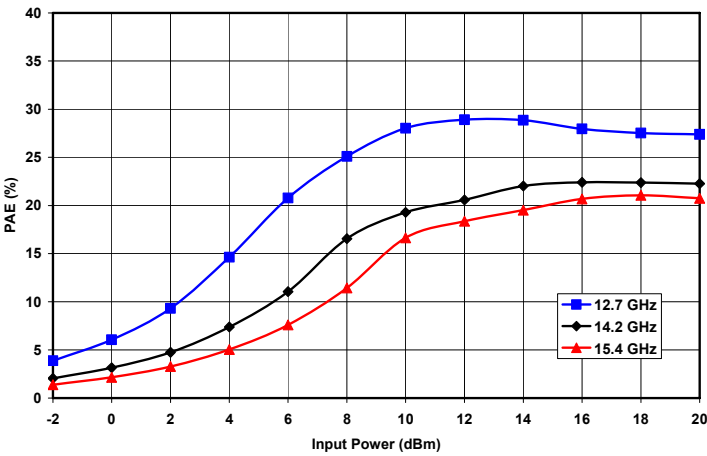


Figure 17. Power Added Efficiency vs. Input Power and Frequency at VD = 10V and IDQ = 210mA

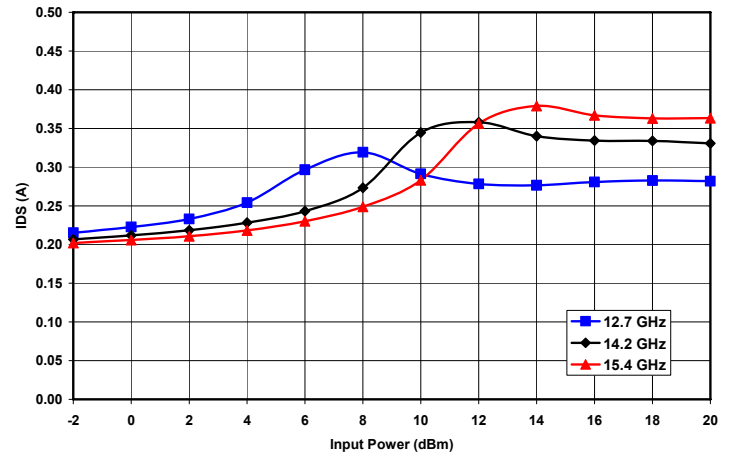


Figure 18. Drain Current vs. Input Power and Frequency at VD = 10V and IDQ = 210mA

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**VD = 6V**

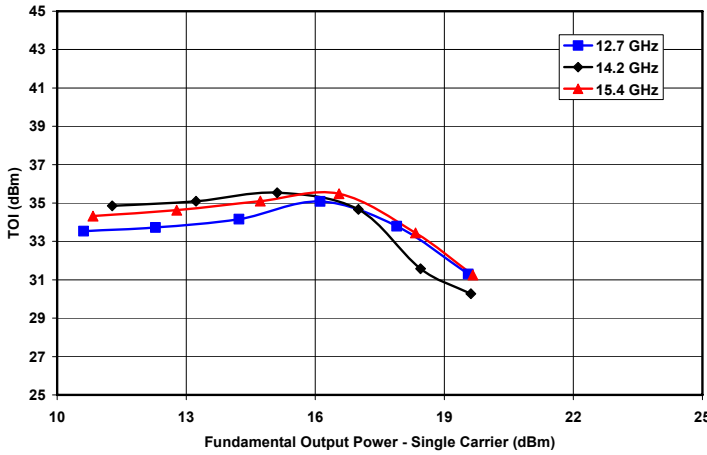


Figure 19. Third Order Intercept vs. Output Power and Frequency at VD = 6V and IDQ =210mA

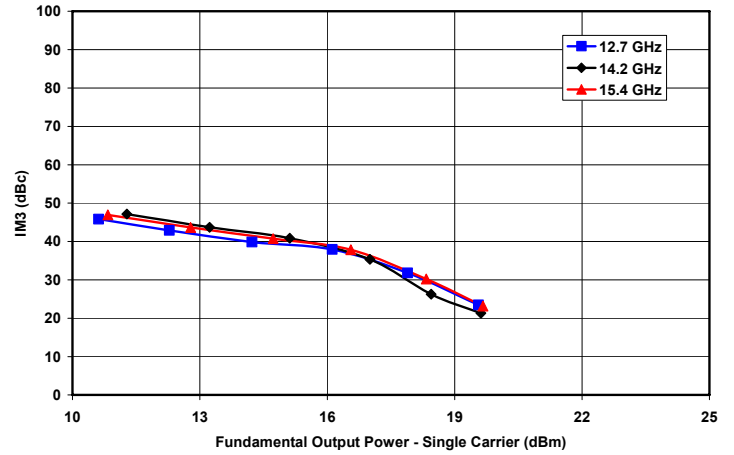


Figure 20. Third Order Intermod vs. Output Power and Frequency at VD = 6V and IDQ =210mA

**VD = 8V**

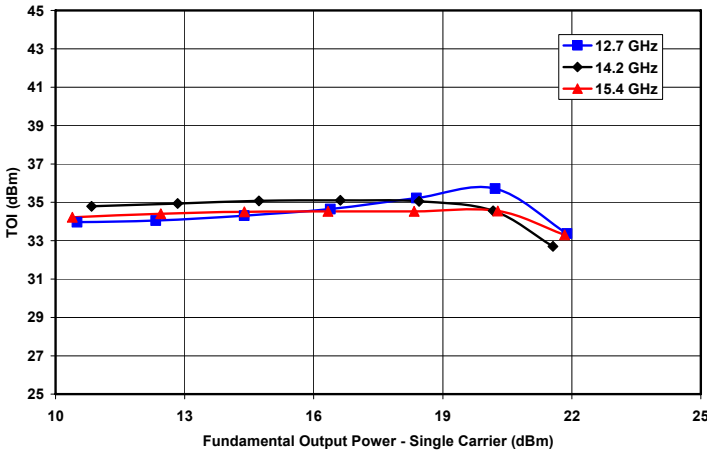


Figure 21. Third Order Intercept vs. Output Power and Frequency at VD = 8V and IDQ =210mA

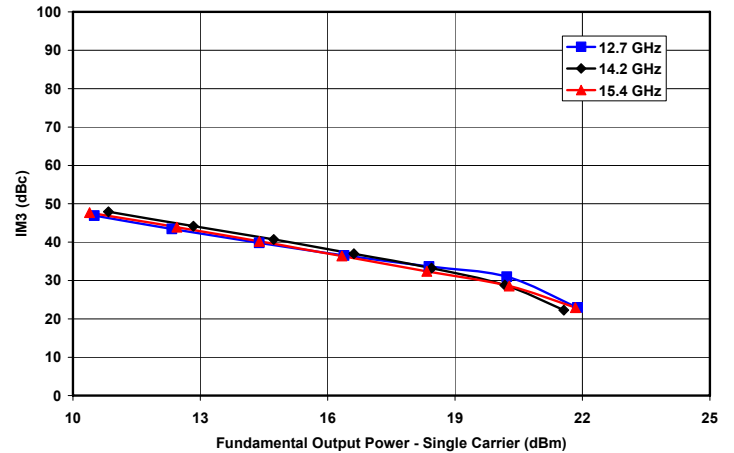


Figure 22. Third Order Intermod vs. Output Power and Frequency at VD = 8V and IDQ =210mA

**VD = 10V**

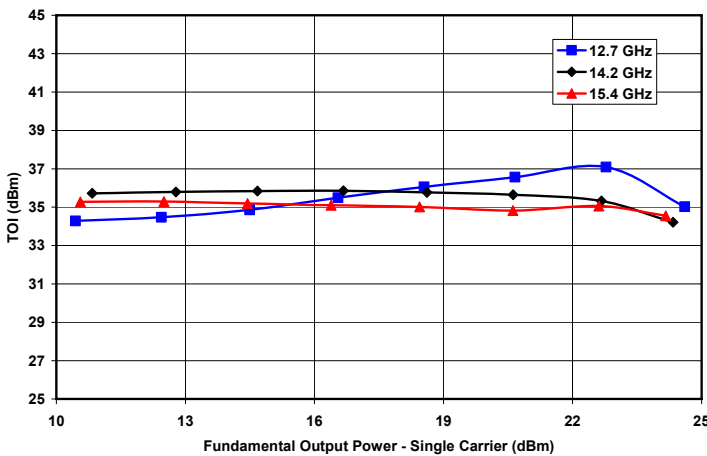


Figure 23. Third Order Intercept vs. Output Power and Frequency at VD = 10V and IDQ =210mA

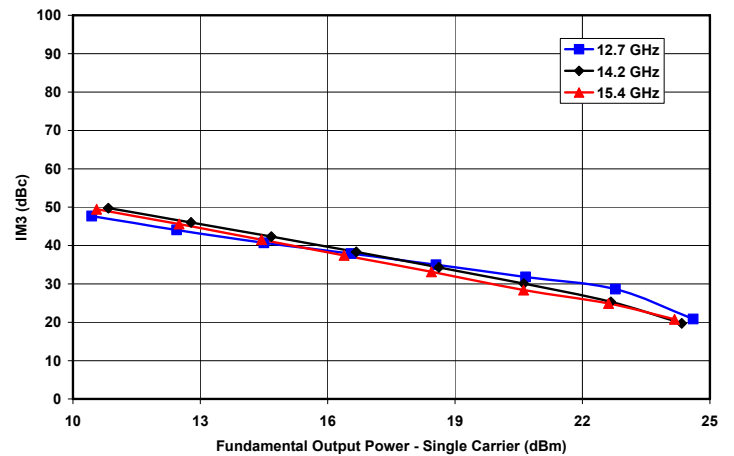


Figure 24. Third Order Intermod vs. Output Power and Frequency at VD = 10V and IDQ =210mA

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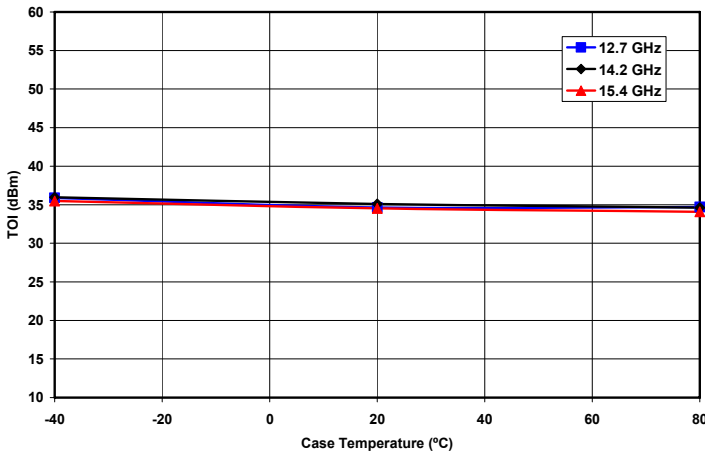


Figure 25. Third Order Intercept vs. Case Temperature and Frequency at Single Carrier Output Power Level = 16 dBm, VD = 8V and IDQ =210mA

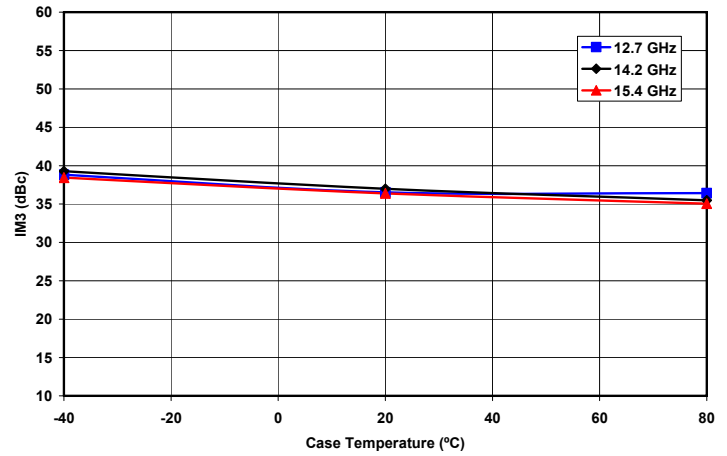
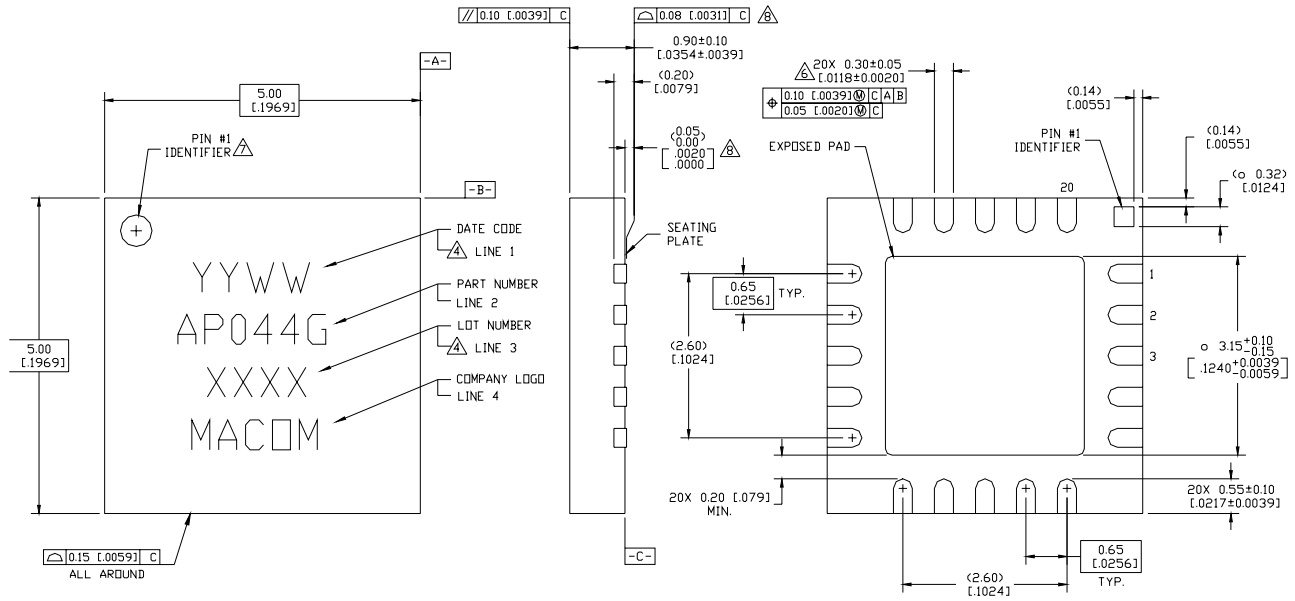


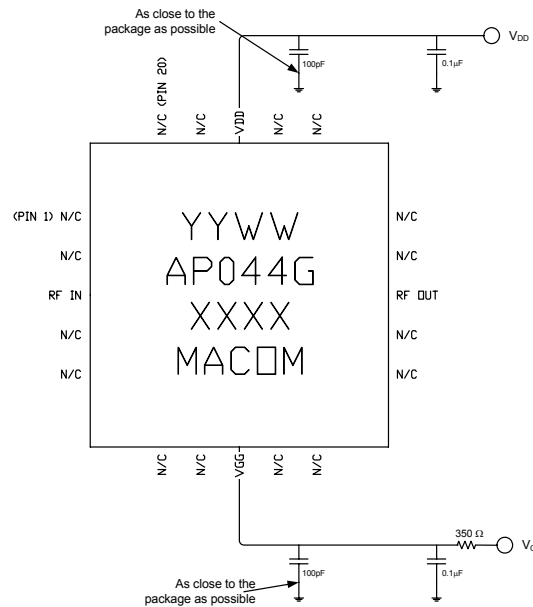
Figure 26. Third Order Intermod vs. Case Temperature and Frequency at Single Carrier Output Power Level = 16 dBm, VD = 8V and IDQ =210mA

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**Figure 27. 5x5 mm 20-Lead MLP.**



**Figure 28. Recommended Bias Configuration.**

Note: The exposed pad centered on the package bottom must be connected to RF and dc ground for proper electrical and thermal operation.

Refer to M/A-COM Application Note **Surface Mounting Instructions for PQFN Packages #S2083\*** for assembly guidelines.

**Additional Precaution: All parts must receive a bake-out of 125°C for 24 hours prior to any solder reflow operation.**

\*Application Notes can be found by going to the Site Search Page of M/A-COM's web page (<http://www.macom.com/search/search.jsp>) and searching for the required Application Note.



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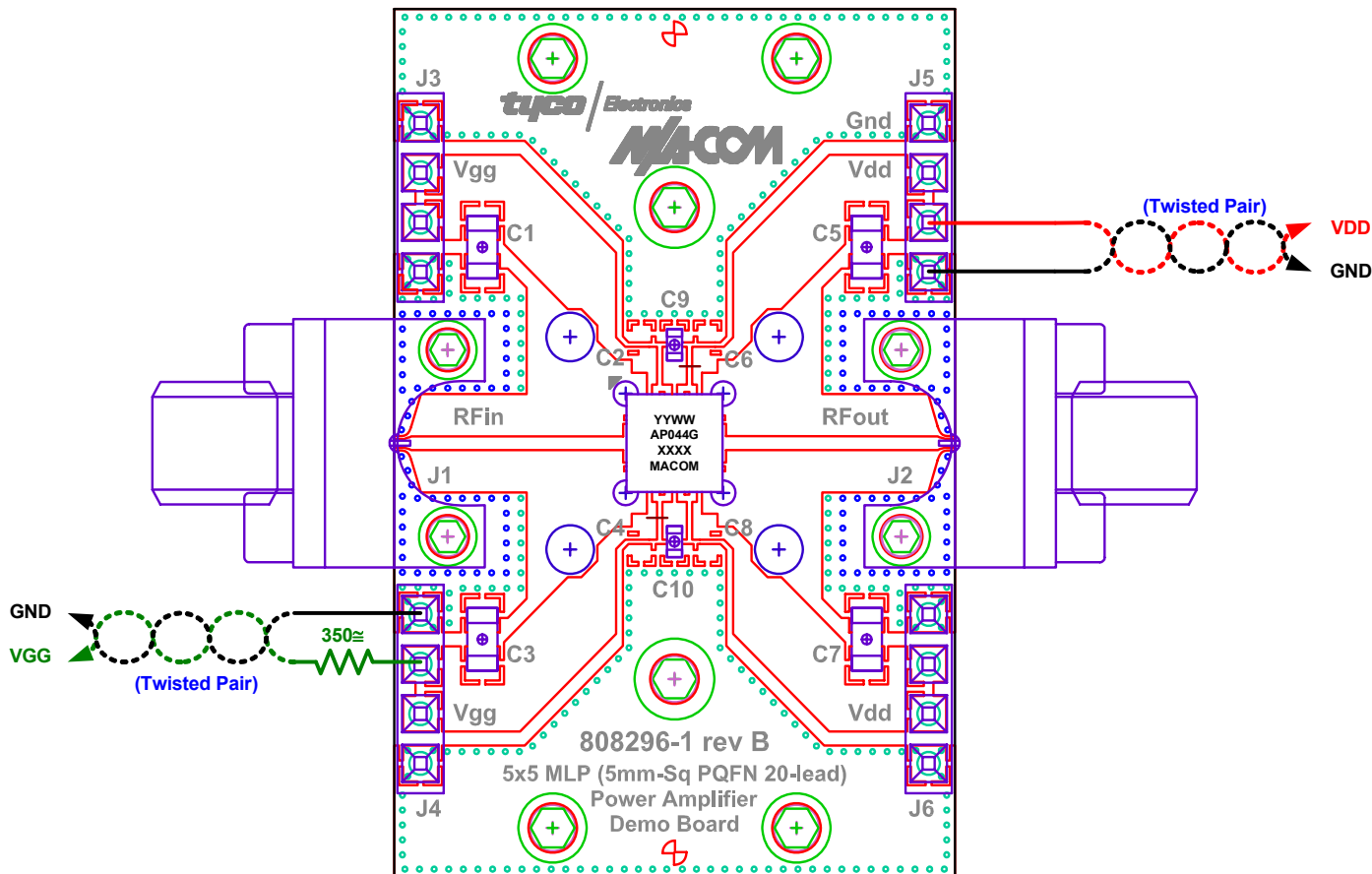


Figure 29. Demonstration Board PN MAAP-000044-SMB003 (available upon request).